

TOPOLOGICAL INSULATORS

Ümit Ertem

GRM-2014 Workshop & Summer School

9-11 July 2014, İYTE, İzmir

- Graphene

- Graphene and Dirac Equation
- Symmetries and Mass Terms in Graphene

- What is a Topological Insulator?

- Chern Insulators

- Bloch States, Berry Connection and Curvature
- Chern Number
- Haldane Model
- Chiral Edge States

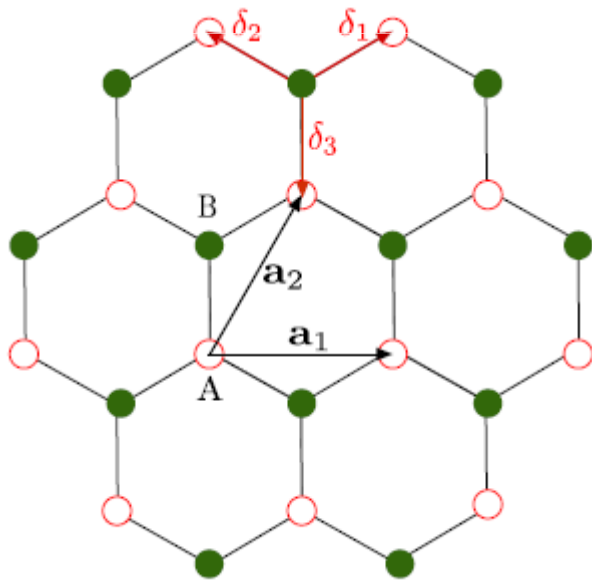
- \mathbb{Z}_2 Insulators

- TR Symmetry, Kramers Pairs, TRIM Points
- Kane-Mele Model
- Helical Edge States
- \mathbb{Z}_2 Invariants
- Experimental Realizations: BHZ Model

Graphene

- Graphene and Dirac Equation
- A **honeycomb** lattice of carbon atoms with two sublattices

A and B



triangular **Bravais lattice** basis vectors:

$$\vec{a}_1 = \sqrt{3}a\vec{e}_x \quad \vec{a}_2 = \frac{a}{2}(\sqrt{3}\vec{e}_x + 3\vec{e}_y)$$

$a = 0,142 \text{ nm}$ is the length of the C-C bond.

The vectors connecting any A-site to its three B-site **nearest neighbours**;

$$\vec{\delta}_{1,2} = \frac{a}{2}(\pm\sqrt{3}\vec{e}_x + \vec{e}_y) \quad \vec{\delta}_3 = -a\vec{e}_y$$

- The **tight-binding** Hamiltonian

$$H = t \sum_{\vec{r}_A} \sum_{\alpha=1}^3 c_B^\dagger(\vec{r}_A + \vec{\delta}_\alpha) c_A(\vec{r}_A) + h.c.$$

where $t \cong -2.7 \text{ eV}$ is the **hopping amplitude** between two adjacent carbon atoms.

- c_A **destroys** a fermion at site \vec{r}_A and c_B^\dagger **creates** a fermion at site $\vec{r}_A + \vec{\delta}_\alpha$
-

- By doing the **Fourier transformation**

$$c_a(\vec{r}_i) = \frac{1}{\sqrt{N}} \sum_{\vec{k}} e^{-i\vec{k} \cdot \vec{r}_i} c_a(\vec{k})$$

one obtains the **Hamiltonian** in the form

$$H = \sum_{\vec{k}} c_a^\dagger(\vec{k}) [h(\vec{k})]_{ab} c_b(\vec{k})$$

- $h(\vec{k})$ is the **Bloch Hamiltonian**

$$h(\vec{k}) = d_1(\vec{k})\sigma_1 + d_2(\vec{k})\sigma_2$$

σ_i are **Pauli matrices** and

$$d_1(\vec{k}) = t \sum_{\alpha=1}^3 \cos(\vec{k} \cdot \vec{\delta}_\alpha) \quad d_2(\vec{k}) = t \sum_{\alpha=1}^3 \sin(\vec{k} \cdot \vec{\delta}_\alpha)$$

hence, $d_1(\vec{k})$ is **even** and $d_2(\vec{k})$ is **odd** functions

$$d_1(-\vec{k}) = d_1(\vec{k}) \quad d_2(-\vec{k}) = -d_2(\vec{k})$$

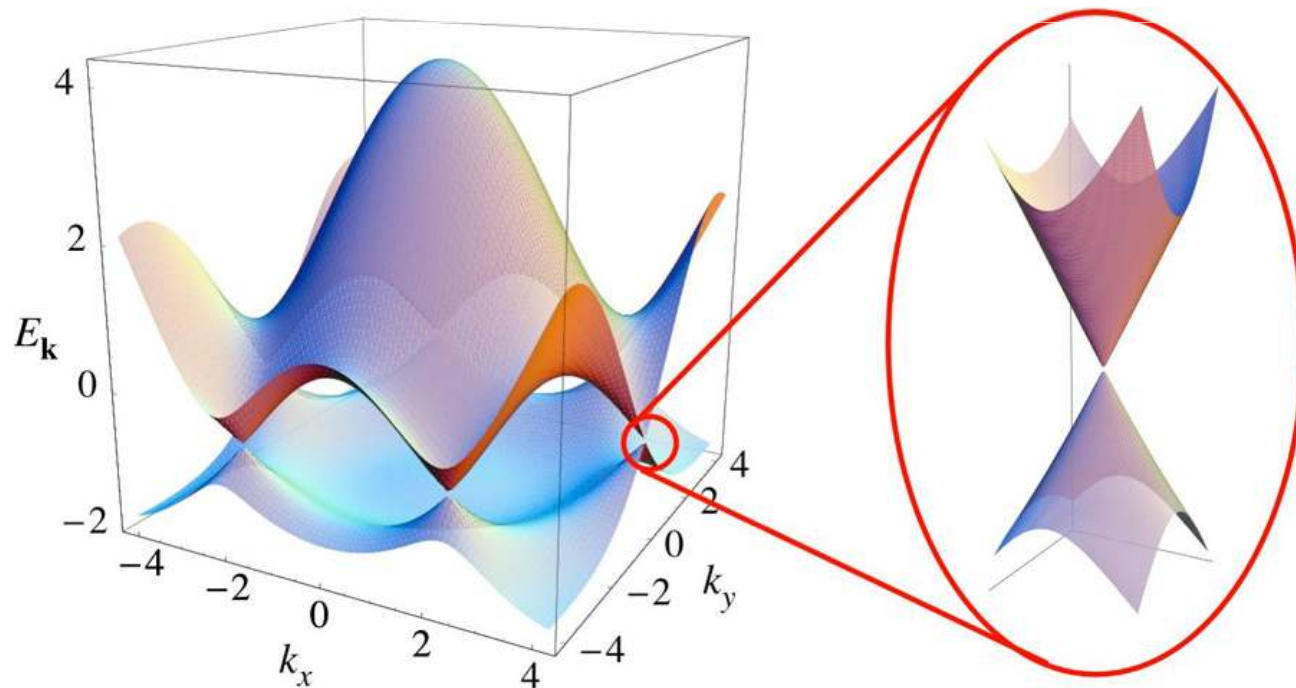
- Corresponding **energy spectrum** is given by the length of the vector $\vec{d} = (d_1, d_2)$

$$E(\vec{k}) = \pm |\vec{d}(\vec{k})| = \pm \sqrt{d_1(\vec{k})^2 + d_2(\vec{k})^2}$$

which describes a **valence band** (minus sign) and a **conduction band** (plus sign) that are symmetric w.r.t. $E = 0$

- The valence and conduction bands touch at **isolated points of the BZ**, which are obtained by solving the equation $\vec{d}(\vec{k}) = 0$
- There are only **two** inequivalent such points called **Dirac points** located at

$$\vec{k} = \pm \vec{K} = \pm \frac{4\pi}{3\sqrt{3}a} \vec{e}_x$$



- We consider the **low-energy theory** near the Dirac points.
- The **momenta** close to the zero-energy points are ($|\vec{q}|a \ll 1$)

$$\vec{k} = \pm \vec{K} + \vec{q}$$

-
- By expanding to first-order in momenta, **the Hamiltonian** describing the **low energy excitations** near $\vec{k} = \pm \vec{K}$ is found as

$$H^{(\pm\vec{K})} = v_F \sum_{\vec{k}} \begin{pmatrix} c_{A\pm\vec{K}}^\dagger(\vec{q}) & c_{B\pm\vec{K}}^\dagger(\vec{q}) \end{pmatrix} \begin{pmatrix} 0 & \pm q_x - iq_y \\ \pm q_x + iq_y & 0 \end{pmatrix} \begin{pmatrix} c_{A\pm\vec{K}}(\vec{q}) \\ c_{B\pm\vec{K}}(\vec{q}) \end{pmatrix}$$

where $v_F = -\frac{3at}{2} \cong 10^6 \text{ m/s} \cong c/300$ is the **Fermi velocity** and

$$c_{A\pm\vec{K}} = c_A(\pm\vec{K} + \vec{q}) \quad \vec{q} = q_x \vec{e}_x + q_y \vec{e}_y$$

- Using the convenient spinor representation

$$c_{\alpha}^{\dagger}(\vec{q}) = \left(c_{AK}^{\dagger} \quad c_{BK}^{\dagger} \quad c_{A-K}^{\dagger} \quad c_{B-K}^{\dagger} \right)$$

the Hamiltonian can be written in the **Bloch** form

$$H = \sum_{\vec{q}} \sum_{\alpha, \beta=1}^4 c_{\alpha}^{\dagger}(\vec{q}) \left[v_F (q_x \sigma_1 \tau_3 + q_y \sigma_2) \right]_{\alpha\beta} c_{\beta}(\vec{q})$$

which has exactly the form of the the **Dirac Hamiltonian** describing the spin-1/2 relativistic particles with zero mass.
 (τ_3 is the Pauli matrix acts on K,-K points)

- Corresponding dispersion relation is **linear** in momentum

$$E(\vec{q}) = v_F |\vec{q}|$$

which is typical for a relativistic massless particle, with the velocity of light replaced by the Fermi velocity.

• Symmetries and Mass Terms in Graphene

- Dirac points are robust as long as some **fundamental symmetries** are obeyed.
 - These fundamental symmetries are
 - **Time-reversal** (TR) symmetry T
 - **Inversion** symmetry P
-

- Inversion operator

$$P : (x, y) \rightarrow (-x, -y)$$

If $[H, P] = 0$, then the Hamiltonian has **inversion symmetry**.

- Effect of P on Pauli matrices and Bloch Hamiltonian

$$P : (\sigma_1, \sigma_2, \sigma_3) \rightarrow (\sigma_1, -\sigma_2, -\sigma_3)$$

$$Ph(\vec{k})P^{-1} = h(-\vec{k})$$

- Inversion is represented by $P = \sigma_1$ and the graphene Bloch Hamiltonian is **invariant under inversion** ($d_1(\vec{k})$ even, $d_2(\vec{k})$ odd)

$$Ph(\vec{k})P^{-1} = \sigma_1 \left(d_1(\vec{k})\sigma_1 + d_2(\vec{k})\sigma_2 \right) \sigma_1 = h(-\vec{k})$$

- TR operation

$$T : t \rightarrow -t$$

If $[H, T] = 0$, then the Hamiltonian has **TR symmetry**.

- Effect of **T** on Pauli matrices and Bloch Hamiltonian

$$T : (\sigma_1, \sigma_2, \sigma_3) \rightarrow (\sigma_1, -\sigma_2, \sigma_3)$$

$$Th(\vec{k})T^{-1} = h(-\vec{k})$$

- TR operation is represented by $T = \sigma_0 K$ and the graphene Bloch Hamiltonian is **invariant under TR**

($\sigma_0 = I$ and K is complex conjugation)

$$\begin{aligned} Th(\vec{k})T^{-1} &= \sigma_0 \left(d_1^*(\vec{k})\sigma_1 - d_2^*(\vec{k})\sigma_2 \right) \sigma_0 \\ &= d_1(-\vec{k})\sigma_1 + d_2(-\vec{k})\sigma_2 \\ &= h(-\vec{k}) \end{aligned}$$

- By breaking one of these symmetries or adding spin degrees of freedom, one can add a **mass term** and open a **gap**.
 - A mass term **anticommutes** with the Hamiltonian, hence it enters as a σ_3 term with possible different coefficient functions $d_3(\vec{k})$.
-

- For example, a generic **two-band model** for spinless fermions on a bipartite lattice can be written as

$$\begin{aligned}
 h(k) &= \varepsilon_0(k)\sigma_0 + d_1(k)\sigma_1 + d_2(k)\sigma_2 + d_3(k)\sigma_3 \\
 &= \varepsilon_0(k)\sigma_0 + \vec{d}(k) \cdot \vec{\sigma}
 \end{aligned}$$

- When the spin is included, there are **16** possible different **mass terms**, some breaks and some respects the symmetries.
- However, we consider **3 types** of mass terms.
(Semenov, Haldane and Kane-Mele masses)

- *i) Semenov mass*
- The simplest choice of a mass term is

$$d_3(k) = M_S$$

- It enters to the Hamiltonian as a staggered on-site potential term that **breaks inversion** and **respects TR**

$$H_1 = \sum_i M_{S_i} c_i^\dagger c_i$$

($i = A, B$ and $M_{S_A} = -M_{S_B}$)

- The mass term is independent of k and has **same sign** at K and $K' = -K$ points.
- Dispersion relation becomes

$$E^2 = v_F^2 p^2 + M_S^2$$

- ii) Haldane mass
- Another possibility is adding a **phase** to the **second-neighbour hopping** term in the Hamiltonian.
- This is done by **magnetic fluxes** ϕ and breaks TR symmetry,

$$H_2 = t_2 \sum_{i=1}^3 \left(\sum_{r_A} c_A^\dagger(r_A) c_A(r_A + b_i) e^{i\phi} + \sum_{r_B} c_B^\dagger(r_B) c_B(r_B + b_i) e^{-i\phi} \right) + h.c.$$

- This gives a **mass term** in Dirac Hamiltonian at K and K' points

$$d_3(k \cong \pm K) = \mp 3\sqrt{3}t_2 \sin \phi$$

- **Sign** of the mass term at K and K' is **different**.
- Dispersion relation becomes

$$E^2 = v_F^2 p^2 + 27t_2^2 \sin^2 \phi$$

- iii) Kane-Mele mass
- By adding **spin** degrees of freedom, one can write a mass term that **respects** inversion and TR symmetries.
- This corresponds to the **intrinsic spin-orbit coupling** term,

$$H_3 = i\lambda_{SO} \sum_{\langle\langle i,j \rangle\rangle} v_{ij} c_{i\alpha}^\dagger (s_3)_{\alpha\beta} c_{j\beta}$$

where $v_{ij} = \pm 1$ and s_3 is the physical spin of the electrons ($s_3 = \begin{pmatrix} 1 & 0 \\ 0 & -1 \end{pmatrix}$).

- This gives a mass term

$$d_3(\pm K) = \pm 3\sqrt{3}\lambda_{SO}s_3$$

- Hence, **different signs** at K and K' points.
- Dispersion relation is

$$E^2 = v_F^2 p^2 + 27\lambda_{SO}^2$$

-
- **Different signs of the mass term at K and K' points will give the topological insulator property of the system.**

What is a Topological Insulator?

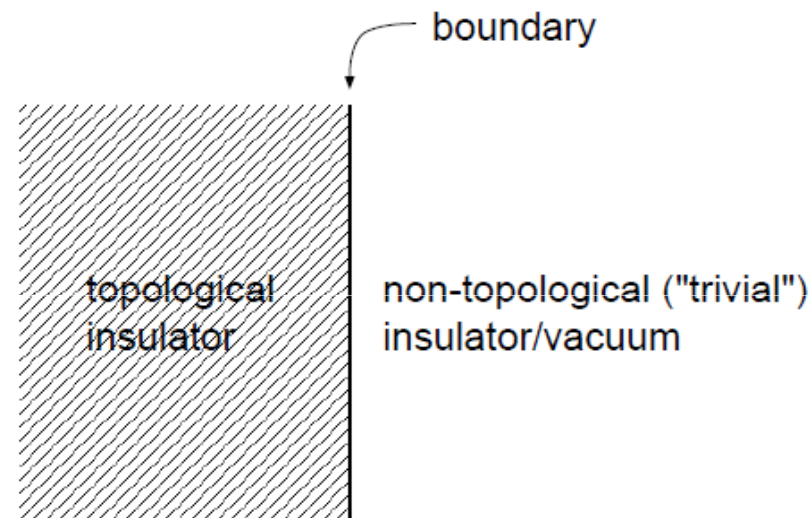
- A **topological insulator (TI)** is an insulator (gapped) in the **bulk** and has also gapless states at the **edge or surface**.

- Topological insulators are characterized by **topological orders**. Different topological orders define different classes of TIs.

- A TI Hamiltonian must be a **gapped** Hamiltonian. A TI Hamiltonian in one topological class **cannot be deformed** continuously to a Hamiltonian in another topological class.
(deformation means changing Hamiltonian parameters without closing the gap)

- To convert one topological class Hamiltonian to another one, there must be a **gapless state** between two classes. Hence, the insulating phase must disappear. These are the **edge states**.

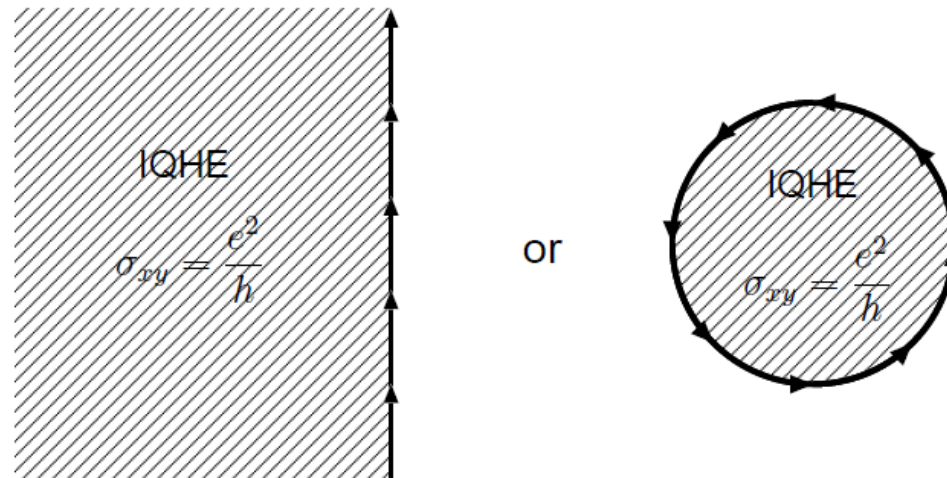
- For example, a **topological insulator** which has an interface with an **ordinary insulator** (or vacuum) has a **gapless boundary**, although insulating at the bulk.



- The gapless boundary degrees of freedom are **robust to perturbations**, as long as these perturbations **do not close** the bulk gap and **preserve** the symmetries of the system.

- There are mainly **two** types of topological insulators;
 - \mathbb{Z} Insulators (Chern Insulators)
 - \mathbb{Z}_2 Insulators

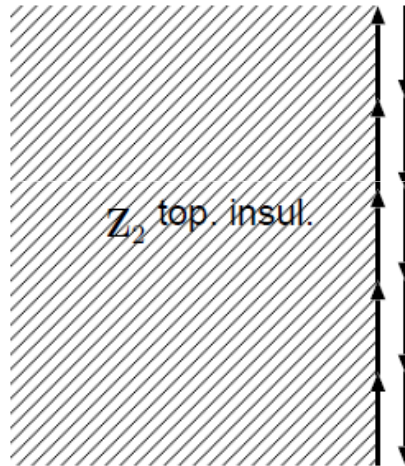
- An example for the first type is the **Integer Quantum Hall Effect (IQHE)**.
- In this case, an applied magnetic field to a d=2 dimensional electron system results a **gapless edge state** which corresponds to a charge current at the edge.



- The applied magnetic field **breaks** TR symmetry.
 - The quantized Hall conductivity σ_{xy} at the edge can take **integer multiples** of e^2 / h .
 - This edge state possesses a **chirality** inherited from the applied magnetic field and propagates only in **one direction**.
-

- IQHE can be generalized to cases without an applied magnetic field by a **TR breaking term** in the Hamiltonian.
- These are called **Chern insulators**.
- The set of different topological classes is \mathbb{Z} . (corresponds to the number of edge states)

- Second type of topological insulators is **Quantum Spin Hall Effect** or \mathbb{Z}_2 Insulators.
- In this case, **TR** symmetry is **conserved** and the edge states propagate in **two opposite directions** (with opposite spin) as pairs.



- Hence, there is **no net charge current** at the edge, however there is non-zero **spin current**.

- There are only **two** different topological classes in this case, hence the name \mathbb{Z}_2 .
 - If there are **even** number of pairs at the edge, we have a **trivial insulator**.
 - If there are **odd** number of pairs at the edge, we have a **topological insulator**.
-

- The **topological class** of a topological insulator Hamiltonian is determined by the **topological invariants**.
- That is **Chern number** for Chern insulators and **\mathbb{Z}_2 invariant** for \mathbb{Z}_2 insulators.

Chern Insulators

- Different topological classes of a **Chern insulator** are characterized by a topological invariant called **Chern number**.
- It is defined from the **eigenstates** of the Hamiltonian.

• Bloch States, Berry Connection and Curvature

- Eigenstates of the Bloch Hamiltonian are called **Bloch states**

$$h(k)|u_n(k)\rangle = E_n(k)|u_n(k)\rangle$$

- Eigenvalues $E_n(k)$ are **periodic** in momentum and all distinct eigenvalues are located in the **first BZ**.

- Eigenstates $|u_n(k)\rangle$ are equivalent **up to a phase**.
- Let us consider a **loop** (closed curve) C in the BZ. Along such a loop the eigenstates acquire a phase

$$|u_n(k)\rangle \rightarrow e^{i\gamma_n} |u_n(k)\rangle$$

where $\gamma_n = \oint_C dk A_n(k)$ is the **Berry phase**.

- The **Berry connection** is defined in terms of the eigenstates as

$$A_n(k) = i \langle u_n(k) | \nabla_k | u_n(k) \rangle$$

- The **Berry curvature** is

$$\begin{aligned} F_n(k) &= \nabla_k \times A_n(k) \\ &= \nabla_k \times \langle u_n(k) | i \nabla_k | u_n(k) \rangle \end{aligned}$$

- Chern Number

- Chern number is defined as the integral of the **Berry curvature** over the BZ

$$C_1 = \frac{1}{2\pi} \int_{BZ} dk F(k)$$

(this is defined in 2D and called the first Chern number, there are generalizations to higher dimensions and $F(k) = \sum_n F_n(k)$)

- Chern number is a **topological invariant** and it takes only **integer** values.
-

- For the IQHE the quantization of **Hall conductivity** is expressed by the Chern number

$$\sigma_H = C_1 \frac{e^2}{h}$$

- Hence, the Chern number gives the **number of chiral edge states** for Chern insulators (and IQHE).
- Its sign determines the **direction of the edge current**.

- In 2D, for the systems with **Bloch Hamiltonian**

$$h(k) = \vec{d}(k) \cdot \vec{\sigma}$$

one can write the **Chern number** as follows

$$C_1 = \frac{1}{4\pi} \int_{BZ} d^2k \left(\frac{\partial \hat{d}(k)}{\partial k_x} \times \frac{\partial \hat{d}(k)}{\partial k_y} \right) \cdot \hat{d}(k)$$

where

$$\hat{d}(k) = \frac{\vec{d}(k)}{|\vec{d}(k)|} \quad \text{and} \quad |\vec{d}(k)| = \sqrt{d_1^2(k) + d_2^2(k) + d_3^2(k)}$$

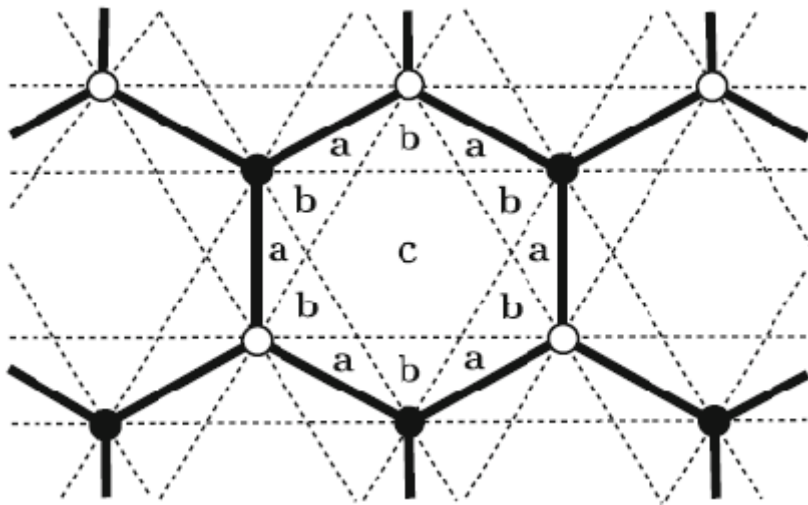
- For **massive** Dirac Hamiltonians, explicit calculation of the Chern number gives the result that it depends only on the **mass term** $d_3(k)$.
- For massive **graphene** Hamiltonians, the **sign of the mass term** at K and K' points determine the value of the Chern number;

$$C_1 = \frac{1}{2} [\text{sgn}(d_3(k) \text{ at } K) - \text{sgn}(d_3(k) \text{ at } K')]$$

- Hence, the mass terms that have **different signs** at K and K' points result a **non-zero Chern number** and a **non-trivial topological insulator** phase.
- If the **sign** of the mass terms at K and K' points are **same**, then the **Chern number is zero** and we have an ordinary **trivial insulator** phase.

• Haldane Model

- Spinless fermion model for the IQHE without Landau levels.
 - QHE may result from the broken TR symmetry without any net magnetic flux through the unit cell of a periodic 2D lattice.
 - We have a graphene honeycomb lattice and a periodic magnetic flux density normal to the plane with the full symmetry of the lattice and with the zero total flux through the unit cell.
-



The flux ϕ_a in the region a and the flux ϕ_b in the region b have the relation $\phi_a = -\phi_b$. and the flux ϕ_c in the region c is $\phi_c = 0$.

Hence, the total flux in the unit cell is zero. (Haldane, PRL 61, 2015 (1988))

- Haldane model **Hamiltonian** is

$$H = M \sum_i \varepsilon_i c_i^\dagger c_i + t_1 \sum_{\langle i,j \rangle} c_i^\dagger c_j + t_2 \sum_{\langle\langle i,j \rangle\rangle} e^{-i v_{ij} \phi} c_i^\dagger c_j$$

-
- The **first term** is inversion-symmetry breaking term with $\varepsilon_i = \pm 1$ that is on-site energies $+M$ for $i = A$ and $-M$ for $i = B$.
 - Second term is the **nearest-neighbour** hopping term.
 - Third term is the **second-nearest-neighbour** hopping term with a phase and

$$\phi = \frac{2\pi}{\phi_0} (2\phi_a + \phi_b)$$

$$\phi_0 = h/c \quad \text{and} \quad v_{ij} = \pm 1$$
 gives the **different phases** for different hopping terms.

- After doing Fourier transformation, one obtains the two-band **Bloch Hamiltonian** as follows;

$$h(k) = d_i(k) \cdot \sigma_i$$

where

$$d_0(k) = \varepsilon(k) = 2t_2 \cos \phi \sum_i \cos(\vec{k} \cdot \vec{b}_i)$$

$$d_1(k) = t_1 \sum_i \cos(\vec{k} \cdot \vec{a}_i)$$

$$d_2(k) = t_1 \sum_i \sin(\vec{k} \cdot \vec{a}_i)$$

$$d_3(k) = M - 2t_2 \sin \phi \sum_i \sin(\vec{k} \cdot \vec{b}_i)$$

here \vec{a}_i are Bravais lattice basis vectors and

$$\vec{b}_1 = \vec{a}_2 - \vec{a}_3 \quad , \quad \vec{b}_2 = \vec{a}_3 - \vec{a}_1 \quad , \quad \vec{b}_3 = \vec{a}_1 - \vec{a}_2$$

- By considering **low energy limit** at K and K' points, we obtain the Bloch Hamiltonians;

$$h(K + k) = -3t_2 \cos \phi + \frac{3}{2} at_1 (-k_x \sigma_1 - k_y \sigma_2) + (M + 3\sqrt{3}t_2 \sin \phi) \sigma_3$$

$$h(K' + k) = -3t_2 \cos \phi + \frac{3}{2} at_1 (k_x \sigma_1 - k_y \sigma_2) + (M - 3\sqrt{3}t_2 \sin \phi) \sigma_3$$

- Hence, we have the **mass terms** at K and K' points

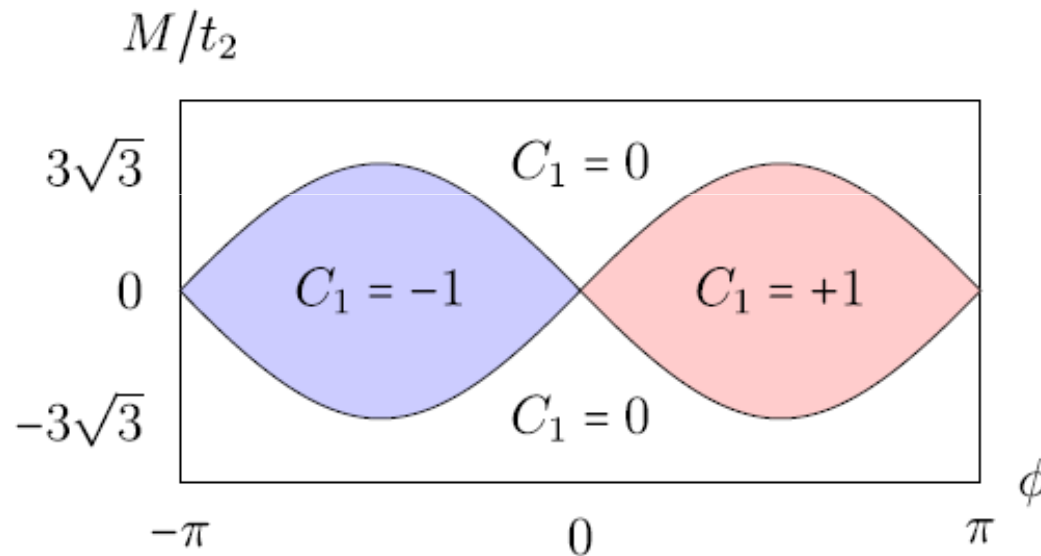
$$d_3(K) = M + 3\sqrt{3}t_2 \sin \phi \qquad d_3(K') = M - 3\sqrt{3}t_2 \sin \phi$$

- Consequently, we can find the **Chern number** as follows

$$C_1 = \frac{1}{2} \left[\text{sgn}(M + 3\sqrt{3}t_2 \sin \phi) - \text{sgn}(M - 3\sqrt{3}t_2 \sin \phi) \right]$$

- We consider **three** cases;
- i) $M = 3\sqrt{3}t_2 \sin \phi$ or $M = -3\sqrt{3}t_2 \sin \phi$
- In this case, the Hamiltonian is **gapless** at K' and **gapped** at K
or **gapless** at K and **gapped** at K'
- ii) for $M > 3\sqrt{3}t_2 \sin \phi$
- In this case, Chern number is **zero**.
So, we have a **trivial insulator**.
- iii) for $M < 3\sqrt{3}t_2 \sin \phi$
- In this case, Chern number is **+1** for $\phi > 0$ and **-1** for $\phi < 0$
So, we have the **topological insulator** phase.

- By deforming the Hamiltonian parameters, we obtain **different topological phases** and between them there is a **gapless transition point**.
- The **phases** of the Haldane model and **Chern numbers** are given as the following diagram;



- For $\phi = 0$ (**no magnetic fluxes**), Haldane model reduces to an ordinary insulator and there are no topological phases ($C_1 = 0$).

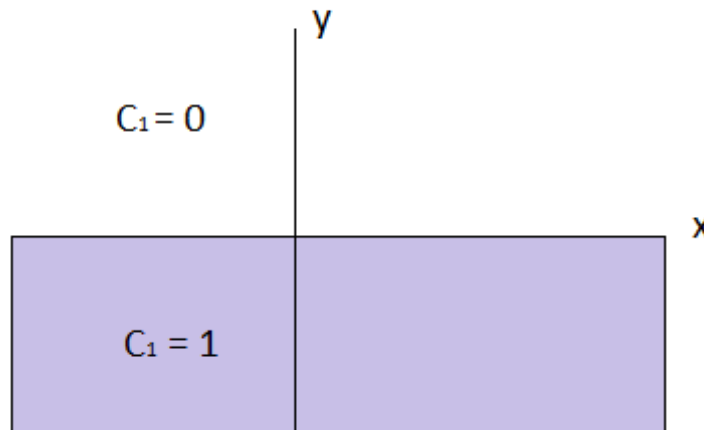
- Chiral Edge States

- TIs are characterized by their **gapless edge states**.

For Chern insulators, there are **chiral** edge states (edge states that go in **one direction**).

- Since the Chern number is a **topological quantity**, it cannot change simply through a continuous transformation, but only at a phase transition associated with a **gap closing**.
-

- Let us consider an **interface** at $y=0$ between a non-trivial insulator with $C_1 = 1$ for $y < 0$ and a trivial insulator with $C_1 = 0$ for $y > 0$



- Consider the **mass terms** of the Haldane model

$$m = d_3(K) = M + 3\sqrt{3}t_2 \sin \phi$$

$$m' = d_3(K') = M - 3\sqrt{3}t_2 \sin \phi$$

-
- Necessarily, one of the mass terms **changes sign** at the interface:

$m'(y < 0) < 0$ and $m'(y > 0) > 0$, whereas the other one has constant sign $m > 0$.

- This is because of the **Chern number**

$$C_1 = \frac{1}{2}(\text{sgn}(m) - \text{sgn}(m'))$$

- Then, it is natural to set $m(0) = 0$, which implies that the **gap closes** at the interface.

- As the mass m depends on the position, by doing a unitary transformation the Bloch Hamiltonian for the Haldane model at K' point leads to the **eigenvalue equation**;

$$\begin{pmatrix} -i\partial_x & \partial_y + m'(y) \\ -\partial_y + m'(y) & i\partial_x \end{pmatrix} \begin{pmatrix} \alpha \\ \beta \end{pmatrix} = E \begin{pmatrix} \alpha \\ \beta \end{pmatrix}$$

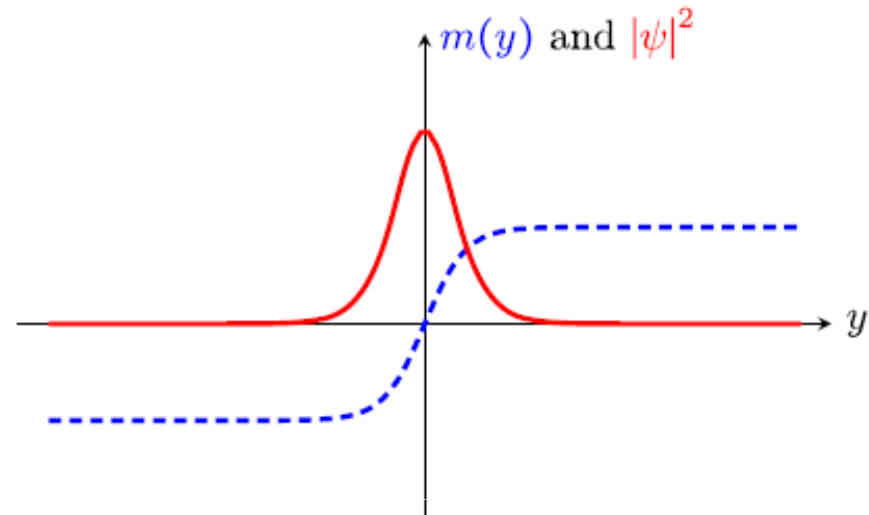
-
- For our choice of $m'(y)$, there is only **one** normalizable **solution**;

$$\Psi_{k_x}(x, y) \propto e^{ik_x x} \exp\left(-\int_0^y m'(y') dy'\right) \begin{pmatrix} 1 \\ 1 \end{pmatrix}$$

for the **energy**

$$E(k_x) = \hbar v_F k_x$$

- This solution is **localized** transverse to the interface where m' changes sign;



- The edge state crosses the Fermi energy at $k_x = 0$, with a **positive** group velocity v_F and thus corresponds to a '**chiral right moving**' edge state.

-
- When considering a transition from an insulator with $C_1 = -1$ to the $C_1 = 0$, the eigenvalue becomes $E(k_x) = -\hbar v_F k_x$ and it has a **negative** group velocity and '**chiral left moving**' edge state.

\mathbb{Z}_2 Insulators

- \mathbb{Z}_2 insulators are characterized by **TR symmetry** and spin-orbit interaction play a prominent role.
- Different topological classes are defined by \mathbb{Z}_2 invariants which take only **two values**.

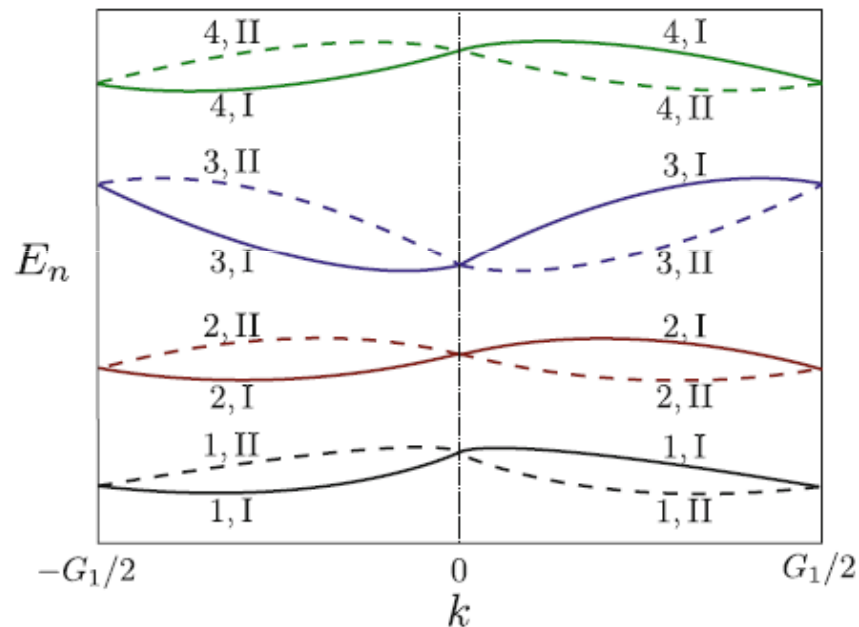
• TR Symmetry, Kramers' Pairs, TRIM Points

- For **spin 1/2** particles TR operation has the property $T^2 = 1$.
- Over the BZ of the system, the **TR operation** relates the Bloch states at **k** with the Bloch states at **-k**.
- Bloch Hamiltonian at **k** and **-k** satisfy

$$h(-k) = Th(k)T^{-1}$$

- TR implies the existence of **Kramers' pairs** of eigenstates:
Any eigenstate of $h(k)$ at k is an eigenstate of $h(-k)$ at $-k$ with the **same energy**.

- So, all eigenstates can be labelled by **pairs**;



We denote **I, II** as Kramers' pairs index and $n = 1, \dots, N$ as non-Kramers' pairs index.

Kramers pairs eigenstates are **orthogonal** to each other.

- TR transforms eigenstates at k of bands **I** into eigenstates at $-k$ of bands **II** and vice versa, but only **up to a phase factor**,

$$\left| u_n^I(-k) \right\rangle = e^{i\chi_{k,n}} T \left| u_n^{II}(k) \right\rangle$$

- Some points of the BZ are **invariant** under TR operation. These points are called **TR invariant momentum (TRIM)** or high symmetry points.
 - These are **fixed points** of T and play an important role in TR invariant systems.
-

- At **TRIM** points **Kramers' pairs are degenerate**. (Since Kramers' pairs are orthogonal and possess the same energy, the spectrum is necessarily always degenerate at TRIM points.)
- Kramers' pairs and TRIM points can be used in defining **topological invariants** for TR invariant systems, and these invariants define the **topological class** of the system.

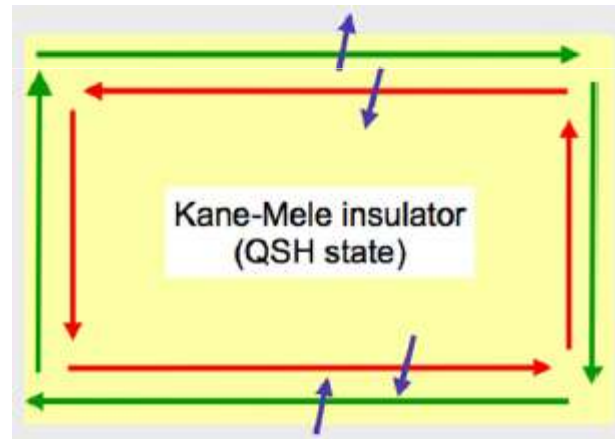
- Kane-Mele Model

- The **Haldane model** of a Chern insulator shows that a non-trivial insulator with a non-zero Chern number can exist when **TR symmetry is broken**.
- Kane and Mele generalized the Haldane model to the graphene lattice model of electrons with **spin 1/2**.
(Kane and Mele, PRL 95, 146802 (2005))

-
- They introduced the **spin-orbit coupling** between electron spin and momentum to replace the periodic magnetic flux and predicted a new quantum phenomenon; the **quantum spin Hall effect (QSHE)**.
 - Unlike the QHE in which the magnetic field **breaks** TR symmetry, the spin-orbit coupling **preserves** TR symmetry.

- In a system with **TR symmetry**, electrons with **spin-up** in the edge channel flow in **one direction** ($C_1 = 1$), while electrons with **spin-down** flow in the **opposite direction** ($C_1 = -1$)
the net **charge current** in two edge channels is **zero**;

$$I_c = I_{\uparrow} + I_{\downarrow} = 0$$



- Instead, a pure **spin current** circulates around the boundary of the system;

$$I_s = \frac{\hbar}{2e} (I_{\uparrow} - I_{\downarrow})$$

- The **Kane-Mele** model for the QSHE is a graphene model with the TR invariant **spin-orbit coupling**;

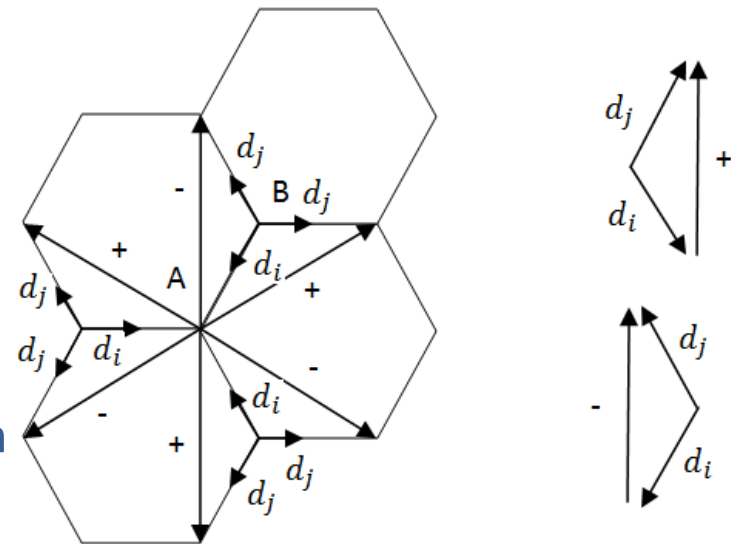
$$H = t \sum_{\langle i,j \rangle} c_i^\dagger c_j + i\lambda_{SO} \sum_{\langle\langle i,j \rangle\rangle} v_{ij} c_i^\dagger s_z c_j + i\lambda_R \sum_{\langle i,j \rangle} c_i^\dagger (\vec{s} \times \vec{d}_{ij})_z c_j + \lambda_v \sum_i \varepsilon_i c_i^\dagger c_i$$

- The **first term** is the nearest neighbour hopping term on a graphene lattice, where $c_i^\dagger = (c_{i\uparrow}^\dagger, c_{i\downarrow}^\dagger)$, $i = A, B$
- The **second term** is an **intrinsic spin-orbit** interaction, which involves spin-dependent second neighbour hopping.

Here
$$v_{ij} = \frac{2}{\sqrt{3}} (\vec{d}_i \times \vec{d}_j)_z = \pm 1$$

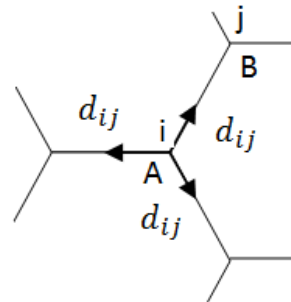
where d_i and d_j are two unit vectors along the two bonds the electron traverses going from site j to i .

The Pauli matrices s_i describe the electron spin.



- The **third term** is the nearest neighbour **Rashba spin-orbit** coupling term.

Here \vec{d}_{ij} is the distance between nearest neighbour sites;



This term corresponds to the application of an electric field in the plane.

- The **last term** is the inversion symmetry breaking term (symmetry breaking w.r.t. $A \leftrightarrow B$)

$\varepsilon_i = \pm 1$ depending on whether i is the A or B site (on-site energy term).

- We can obtain the **Bloch Hamiltonian** of the Kane-Mele model as

$$h(k) = \sum_{a=1}^5 d_a(k) \Gamma_a + \sum_{a<b=1}^5 d_{ab}(k) \Gamma_{ab}$$

- This is written in the basis of Γ_a and Γ_{ab} which are the generators of the **Clifford algebra**

$$\{\Gamma_a, \Gamma_b\} = 2\delta_{ab} \quad a, b = 1, 2, 3, 4, 5$$

and

$$\Gamma_{ab} = \frac{1}{2i} [\Gamma_a, \Gamma_b]$$

- The **representation** for basis matrices for the Kane-Mele model is as follows

$$\Gamma_{1,2,3,4,5} = (\sigma_1 \otimes I, \sigma_3 \otimes I, \sigma_2 \otimes s_1, \sigma_2 \otimes s_2, \sigma_2 \otimes s_3)$$

σ_i represents **sublattice** and s_i represents **spin**.

- The **functions** in the Bloch Hamiltonian are found as

$$d_1 = t \left(1 + 2 \cos \frac{k_x}{2} \cos \frac{\sqrt{3}k_y}{2} \right)$$

$$d_2 = \lambda_v$$

$$d_3 = \lambda_R \left(1 - \cos \frac{k_x}{2} \cos \frac{\sqrt{3}k_y}{2} \right)$$

$$d_4 = -\sqrt{3} \lambda_R \sin \frac{k_x}{2} \sin \frac{\sqrt{3}k_y}{2}$$

$$d_{12} = -2t \cos \frac{k_x}{2} \sin \frac{\sqrt{3}k_y}{2}$$

$$d_{15} = \lambda_{SO} \left(2 \sin k_x - 4 \sin \frac{k_x}{2} \cos \frac{\sqrt{3}k_y}{2} \right)$$

$$d_{23} = -\lambda_R \cos \frac{k_x}{2} \sin \frac{\sqrt{3}k_y}{2}$$

$$d_{24} = \sqrt{3} \lambda_R \sin \frac{k_x}{2} \cos \frac{\sqrt{3}k_y}{2}$$

- For the special case $\lambda_R = 0$, the Hamiltonian split into two independent parts; **spin up** and **spin down** copies of Haldane model.

- By taking the low-energy limit, we have the **Bloch Hamiltonians** at K and K' points as

$$h(K) = \lambda_v \sigma_3 \otimes I + 3\sqrt{3}\lambda_{SO} \sigma_3 \otimes s_3$$

$$h(K') = \lambda_v \sigma_3 \otimes I - 3\sqrt{3}\lambda_{SO} \sigma_3 \otimes s_3$$

here $\sigma_3 \otimes I = \begin{pmatrix} \sigma_3 & 0 \\ 0 & \sigma_3 \end{pmatrix}$ and $\sigma_3 \otimes s_3 = \begin{pmatrix} \sigma_3 & 0 \\ 0 & -\sigma_3 \end{pmatrix}$

- Hence, Bloch Hamiltonians are **diagonal** in s matrices and they can split into **up** and **down** Hamiltonians.
- The **mass terms** are written as

$$d_{3\uparrow}(K) = (\lambda_v + 3\sqrt{3}\lambda_{SO})$$

$$d_{3\downarrow}(K) = (\lambda_v - 3\sqrt{3}\lambda_{SO})$$

$$d_{3\uparrow}(K') = (\lambda_v - 3\sqrt{3}\lambda_{SO})$$

$$d_{3\downarrow}(K') = (\lambda_v + 3\sqrt{3}\lambda_{SO})$$

- Chern numbers

- i) in the case of $\lambda_v > 3\sqrt{3}\lambda_{SO}$

$$C_{1\uparrow} = \frac{1}{2} \left[\text{sgn}(\lambda_v + 3\sqrt{3}\lambda_{SO}) - \text{sgn}(\lambda_v - 3\sqrt{3}\lambda_{SO}) \right] = 0$$

$$C_{1\downarrow} = \frac{1}{2} \left[\text{sgn}(\lambda_v - 3\sqrt{3}\lambda_{SO}) - \text{sgn}(\lambda_v + 3\sqrt{3}\lambda_{SO}) \right] = 0$$

total Chern number $C_{1\uparrow} + C_{1\downarrow} = 0$ and there is **no spin current**, since $C_{1\uparrow} - C_{1\downarrow} = 0$

- ii) in the case of $\lambda_v < 3\sqrt{3}\lambda_{SO}$

$$C_{1\uparrow} = \frac{1}{2} \left[\text{sgn}(\lambda_v + 3\sqrt{3}\lambda_{SO}) - \text{sgn}(\lambda_v - 3\sqrt{3}\lambda_{SO}) \right] = 1$$

$$C_{1\downarrow} = \frac{1}{2} \left[\text{sgn}(\lambda_v - 3\sqrt{3}\lambda_{SO}) - \text{sgn}(\lambda_v + 3\sqrt{3}\lambda_{SO}) \right] = -1$$

total Chern number $C_{1\uparrow} + C_{1\downarrow} = 0$, but there must be **spin currents** because of $C_{1\uparrow} - C_{1\downarrow} \neq 0$

- iii) for $\lambda_v = 3\sqrt{3}\lambda_{SO}$
 - Spin **up** Hamiltonian is **gapless** at K' , but **gapped** at K
 - Spin **down** Hamiltonian is **gapless** at K , but **gapped** at K'
 - So, **total** Hamiltonian is **gapless** both at K and K'
 - Hence, there is a **gapless** state between two different topological phases.
 - The transition point is $\lambda_v = 3\sqrt{3}\lambda_{SO}$ between **two different topological phases** (cases (i) and (ii)).
-
- For $\lambda_R \neq 0$, spin up and spin down will **mix** together and we **cannot separate** the whole system into two independent parts.
 - So, the Chern number is not useful, and we need **\mathbb{Z}_2 invariant** to describe these phases.

• Helical Edge States

- At the boundary between a Kane-Mele topological insulator and a trivial insulator, **helical gapless edge states** occur: the **spin** and the **direction** of these states are tight together.

- Let us consider the Hamiltonian

$$h(k) = d_1(k)\Gamma_1 + d_2(k)\Gamma_2 + d_5(k)\Gamma_5$$

- In **d=2** there are **four TRIM** points λ_i ($i = 0, \dots, 3$)
- The **mass term** of the model is determined by $d_1(\lambda_0)$ and it has **different signs** for trivial and non-trivial insulators.

-
- We have an **interface** at $y=0$ between
 - A **trivial** insulator for $y>0$ where $d_1(\lambda_0) > 0$ and
 - A **topological** insulator for $y<0$ where $d_1(\lambda_0) < 0$

- By defining $m(y) = d_1(\lambda_0)(y)$
we have $m(y > 0) > 0$ and $m(y < 0) < 0$
- The Hamiltonian has **two edge states** solutions

$\psi_{k_x, \uparrow}(x, y) \propto e^{-ik_x x} \exp\left[-\int_0^y m(y') dy'\right] \begin{pmatrix} 0 \\ 1 \\ 0 \\ 0 \end{pmatrix}$	$\psi_{k_x, \downarrow}(x, y) \propto e^{ik_x x} \exp\left[-\int_0^y m(y') dy'\right] \begin{pmatrix} 0 \\ 0 \\ 0 \\ 1 \end{pmatrix}$
--	---

- One is **spin up right moving** state
 - The other is **spin down left moving** state
 - They constitute a **Kramers pairs** of edge states.
-
- If there are **even number of pairs** of edge states, we have a **trivial** insulator
 - If there are **odd number of pairs** of edge states, we have a **topological** insulator.

- \mathbb{Z}_2 Invariants

- \mathbb{Z}_2 invariants are **topological invariants** that characterizes the topological classes of \mathbb{Z}_2 insulators.
 - We have a **TR symmetric** Bloch Hamiltonian $h(k)$ and its eigenstates $|u_i(k)\rangle$. Because of TR symmetry $T|u_i(k)\rangle$ are also eigenstates.
-

- Let us define the **sewing matrix**

$$w_{ij}(k) = \langle u_i(-k) | T | u_j(k) \rangle$$

At **TRIM** points this matrix is antisymmetric.

- For an antisymmetric matrix A , **Pfaffian** can be defined by

$$(\text{Pf } A)^2 = \det A$$

- Hence, the **Pfaffian of the sewing matrix** at TRIM points Λ_k

$$\text{Pf} \left(w_{ij}(\Lambda_k) \right) = \text{Pf} \left(\langle u_i(\Lambda_k) | T | u_j(\Lambda_k) \rangle \right)$$

- The \mathbb{Z}_2 invariant is defined as

$$(-1)^\nu = \prod_{\lambda \in \Lambda_k} \frac{\text{Pf}(w(\lambda))}{\sqrt{\det w(\lambda)}}$$

- At all TRIM points the quantity $\text{Pf} / \sqrt{\det}$ has the value ± 1 .
- The product of ± 1 values gives $+1$ or -1 which corresponds to $\nu = 0$ or $\nu = 1$.

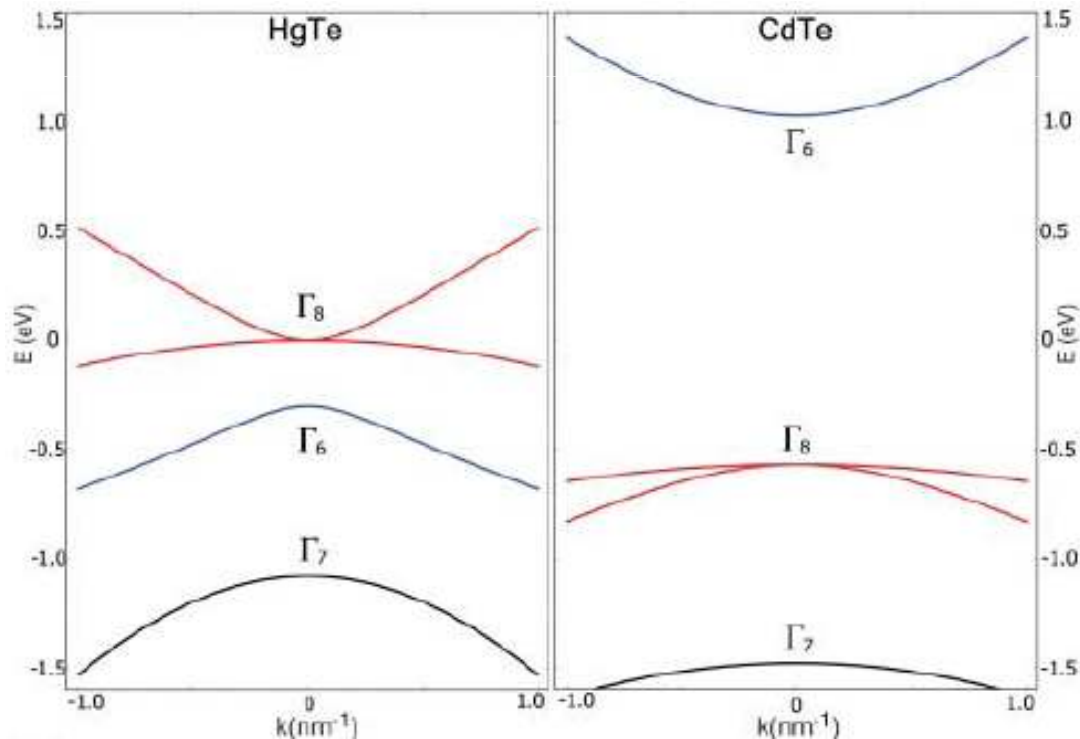
- For $\nu = 0$, topologically trivial class
- For $\nu = 1$, topologically non-trivial class

- The eigenstates $|u_i(k)\rangle$ of the Bloch Hamiltonian $h(k)$ at TRIM points Λ_k determine the topological property of the system.
- Since there are only two topological classes, they are called \mathbb{Z}_2 insulators. (\mathbb{Z}_2 is the group of two elements)

- **Experimental Realizations: BHZ Model**

- SO interaction for graphene is **extremely small**, so the \mathbb{Z}_2 insulator property is experimentally hard to achieve.
- However, effective model of **HgTe/CdTe quantum wells** gives an experimental realization.

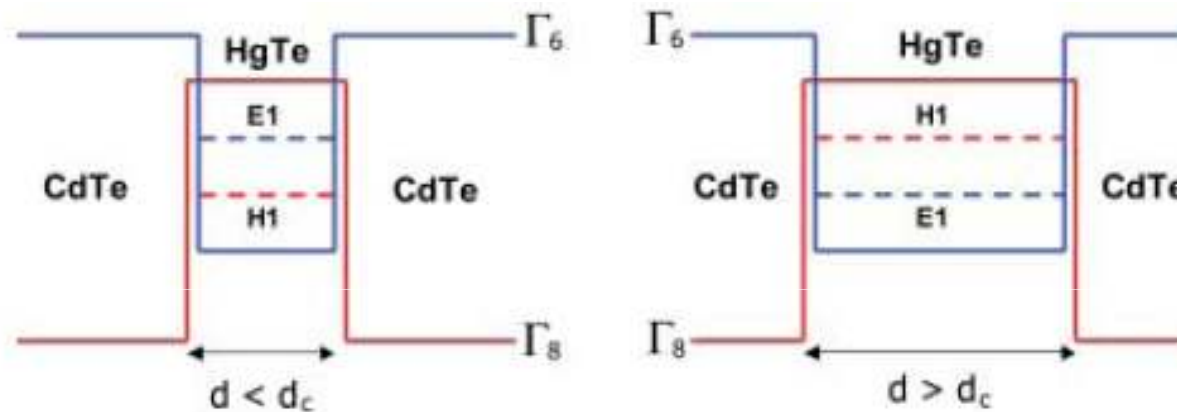
- Band structure of **HgTe** and **CdTe** near the Γ point



CdTe has a **normal** semiconductor **band progression** which is Γ_6 s-type band lying above the Γ_8 p-type band.

HgTe has an **inverted band progression**, where s-type Γ_6 band lies below the p-type Γ_8 band.

- In a CdTe/HgTe/CdTe quantum well, $\Gamma_6 - \Gamma_8$ six bands combine to form an effective four-band model.



- E1** and **H1** are linear combinations of $\Gamma_6 - \Gamma_8$ bands.
- If the **thickness** of the quantum well d is smaller than a critical thickness $d < d_c$ then $E1 > H1$ and if $d > d_c$ then $H1 > E1$.

- **Effective Hamiltonian** of the quantum well is written as

$$H_{eff}(k_x, k_y) = \begin{pmatrix} h(k) & 0 \\ 0 & h^*(-k) \end{pmatrix}$$

where $h(k) = \varepsilon(k)I + d_i(k)\sigma_i$.

- The system has TR symmetry, we can **split** the spin up-down parts.
-
- Components of the **spin up** part are

$$\begin{aligned} \varepsilon(k) &= C - Dk^2 & , & & d_1(k) &= Ak_x \\ d_2(k) &= Ak_y & , & & d_3(k) &= M - Bk^2 \end{aligned}$$

- Hence we have

$$h(k) = C - Dk^2 + A(k_x\sigma_x + k_y\sigma_y) + (M - Bk^2)\sigma_z$$

where A, B, C, D and M are **material parameters** and dependent on the thickness d of the quantum well.

- The **signs** of the A, B, C and D parameters does not change with d
 - However, the sign of M **changes** at the **critical thickness** d_c .
Because M is related to the difference between E1 and H1 bands.
 - Hence, we have a **sign changing** mass term.
-

- The **Chern numbers** for spin up and down cases are found as

$$C_{1\uparrow} = \begin{cases} \pm 1 & , MB > 0 & , d > d_c \\ 0 & , MB < 0 & , d < d_c \end{cases}$$

$$C_{1\downarrow} = \begin{cases} \mp 1 & , MB > 0 & , d > d_c \\ 0 & , MB < 0 & , d < d_c \end{cases}$$

- So, we have a **topological phase** for QW thickness $d > d_c$.
 - For $d < d_c$ we have **ordinary** insulating phase.
-

- For $d > d_c$ we have

$$C_{1\uparrow} + C_{1\downarrow} = 0 \quad \text{and} \quad C_{1\uparrow} - C_{1\downarrow} \neq 0$$

- Hence, there is **spin current** at the edge and there are helical edge states.
 - So, this model is a **\mathbb{Z}_2 topological insulator**.
-

- This model is the **first experimentally realized** topological insulator. (Bernevig, Hughes and Zhang, Science 314, 1757 (2006))
(Molenkamp et al, Science 318, 766 (2007))

Summary

- **Sign changing mass** terms are responsible for the topological insulator property.
- Topological insulators are **bulk insulating** and **edge conducting** systems.
- To deform a Hamiltonian from one topological class to another, one must pass from a **gapless metallic phase**. (These are the edge states)
- There are **two** types of topological insulators: **Chern insulators** and **\mathbb{Z}_2 insulators**.
- Chern insulators are **TR breaking** systems and are characterized by integer topological invariants; **Chern numbers**. They have **chiral** edge states.
Example: Haldane model.
- \mathbb{Z}_2 insulators are **TR invariant** systems and are characterized by two-valued topological invariants; **\mathbb{Z}_2 invariants**. They have **helical** edge states.
Example: Kane-Mele model.
- There are **experimentally realized** materials that have topological insulator property.

... and what else?

- 3D topological insulators
- Classification and periodic table of TI
- Bundle theory and K-theory point of view to TI
- Topological field theory of TI
- Topological superconductors

References

- **Books**
- **Topological Insulators: Dirac Equation in Condensed Matters**, S.-Q. Shen, 2012
- **Topological Insulators and Topological Superconductors**, B. A. Bernevig and T. L. Hughes, 2013
- **Contemporary Concepts of Condensed Matter Science: Topological Insulators**, Eds. M. Franz and L. Molenkamp, 2014
- **Reviews**
- **Colloquium: Topological Insulators**, M. Z. Hasan and C. L. Kane, Rev. Mod. Phys. 82, 3045 (2010)
- **Topological insulators and superconductors**, X.-L. Qi and S.-C. Zhang, Rev. Mod. Phys. 83, 1057 (2011)
- **Introduction to Dirac materials and topological insulators**, J. Cayssol, Comp. Rend. Phys. 14, 760 (2013)
- **An introduction to topological insulators**, M. Fruchart and D. Carpentier, Comp. Rend. Phys. 14, 779 (2013)